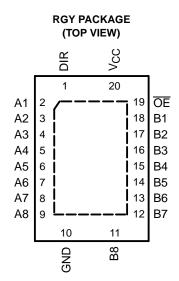




FEATURES

- Optimized for 1.8-V Operation and Is 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- I_{off} Supports Partial-Power-Down Mode Operation
- Sub-1-V Operable
- Max t_{pd} of 1.7 ns at 1.8 V
- Low Power Consumption, 20-μA Max I_{CC}
- ±8-mA Output Drive at 1.8 V
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)



DESCRIPTION/ORDERING INFORMATION

This octal bus transceiver is operational at 0.8-V to 2.7-V V_{CC} , but is designed specifically for 1.65-V to 1.95-V V_{CC} operation.

The SN74AUC245 is designed for asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (OE) input can be used to disable the device so the buses are effectively isolated.

To ensure the high-impedance state during power up or power down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

ORDERING INFORMATION

T _A	PACK	AGE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to 85°C	QFN – RGY	Tape and reel	SN74AUC245RGYR	MS245
	VFBGA – GQN	Tape and reel	SN74AUC245GQNR	MS245

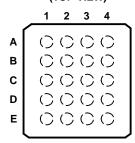
(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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GQN PACKAGE (TOP VIEW)



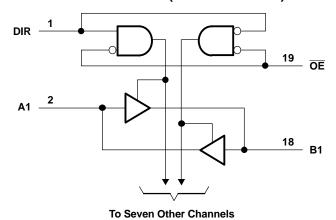
TERMINAL ASSIGNMENTS

	1	2	3	4
Α	A1	DIR	V _{CC}	ŌĒ
В	А3	B2	A2	B1
С	A5	A4	B4	В3
D	A7	В6	A6	B5
Е	GND	A8	B8	В7

FUNCTION TABLE

INP	UTS	ODEDATION				
ŌĒ	DIR	OPERATION				
L	L	B data to A bus				
L	Н	A data to B bus				
Н	X	Isolation				

LOGIC DIAGRAM (POSITIVE LOGIC)



Pin numbers shown are for the RGY package.



SN74AUC245 OCTAL BUS TRANSCEIVER WITH 3-STATE OUTPUTS

Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	3.6	V
VI	Input voltage range ⁽²⁾	Input voltage range ⁽²⁾			
Vo	Voltage range applied to any output in the high	-0.5	3.6	V	
Vo	Output voltage range ⁽²⁾	-0.5	V _{CC} + 0.5	V	
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current	,		±20	mA
	Continuous current through V _{CC} or GND			±100	mA
0	Dealtage thermal impedance	GQN package ⁽³⁾		78	°C/M
θ_{JA}	Package thermal impedance	RGY package (4)		37	°C/W
T _{stg}	Storage temperature range		-65	150	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.
- 3) The package thermal impedance is calculated in accordance with JESD 51-7.
- (4) The package thermal impedance is calculated in accordance with JESD 51-5.

Recommended Operating Conditions⁽¹⁾

			MIN	MAX	UNIT	
V _{CC}	Supply voltage		0.8	2.7	V	
		V _{CC} = 0.8 V	V _{CC}	3.6		
V_{IH}	High-level input voltage	$V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$		3.6	V	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7	3.6		
		V _{CC} = 0.8 V		0		
V_{IL}	Low-level input voltage	V _{CC} = 1.1 V to 1.95 V	0	$0.35 \times V_{CC}$	V	
		V _{CC} = 2.3 V to 2.7 V	0	0.7		
V	Output valtage	Active state	0	V_{CC}	V	
V _O	Output voltage	3-state	0	3.6	V	
		V _{CC} = 0.8 V		-0.7		
		V _{CC} = 1.1 V		-3		
I _{OH}	High-level output current	V _{CC} = 1.4 V		-5	mA	
		V _{CC} = 1.65 V				
		V _{CC} = 2.3 V		-9		
		V _{CC} = 0.8 V		0.7		
		V _{CC} = 1.1 V		3		
I_{OL}	Low-level output current	V _{CC} = 1.4 V		5	mA	
		V _{CC} = 1.65 V		8		
		V _{CC} = 2.3 V		9		
Δt/Δν	Input transition rise or fall rate	1		20	ns/V	
T _A	Operating free-air temperature		-40	85	°C	

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

SCES419A-JANUARY 2003-REVISED MARCH 2005



Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V _{cc}	MIN TYP(1) MAX	UNIT			
	$I_{OH} = -100 \mu A$	0.8 V to 2.7 V	V _{CC} - 0.1				
	$I_{OH} = -0.7 \text{ mA}$	0.8 V	0.55				
V	$I_{OH} = -3 \text{ mA}$	1.1 V	0.8	V			
V _{OH}	$I_{OH} = -5 \text{ mA}$	1.4 V	1	V			
	$I_{OH} = -8 \text{ mA}$	1.65 V	1.2				
	$I_{OH} = -9 \text{ mA}$	2.3 V	1.8				
	$I_{OL} = 100 \mu A$	0.8 V to 2.7 V	0.2				
	$I_{OL} = 0.7 \text{ mA}$	0.8 V	0.25				
V	I _{OL} = 3 mA	1.1 V	0.3	V			
V _{OL}	$I_{OL} = 5 \text{ mA}$	1.4 V	0.4				
	I _{OL} = 8 mA	1.65 V	0.45				
	I _{OL} = 9 mA	2.3 V	0.6				
I _I All inputs	$V_{I} = V_{CC}$ or GND	0 to 2.7 V	±5	μΑ			
I _{off}	V_I or $V_O = 2.7 V$	0	±10	μΑ			
$I_{OZ}^{(2)}$	$V_O = V_{CC}$ or GND	2.7 V	±10	μΑ			
I _{cc}	$V_I = V_{CC}$ or GND, $I_O = 0$	0.8 V to 2.7 V	20	μΑ			
C _i	$V_{I} = V_{CC}$ or GND	2.5 V	2.5 3	pF			
C _{io}	$V_O = V_{CC}$ or GND	2.5 V	7.5 8	pF			

Switching Characteristics

over recommended operating free-air temperature range, C_L = 15 pF (unless otherwise noted) (see Figure 1)

PARAMETER	PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 0.8 V	V _{CC} = ± 0.		V _{CC} = ± 0.			_C = 1.8 : 0.15 V		V _{CC} = ± 0.		UNIT
	(INPOT)	(001701)	TYP	MIN	MAX	MIN	MAX	MIN	TYP	MAX	MIN	MAX		
t _{pd}	A or B	B or A	5	1	3.2	0.6	2	0.5	1	1.7	0.4	1.4	ns	
t _{en}	ŌĒ	A or B	9	1.2	4.9	1	3	0.8	1.2	2.4	0.6	1.8	ns	
t _{dis}	ŌĒ	A or B	9.5	1.9	5.7	1.2	4	0.9	1.9	4.1	0.6	2.9	ns	

Switching Characteristics

over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _C	_C = 1.8 \ : 0.15 V	/	V _{CC} = 1 ± 0.2	UNIT	
	(INPUT)	(OUTPOT)	MIN	TYP	MAX	MIN	MAX	
t _{pd}	A or B	B or A	0.6	1.3	2.2	0.5	1.8	ns
t _{en}	ŌĒ	A or B	1.1	1.5	3	1.1	2.4	ns
t _{dis}	ŌĒ	A or B	1.6	2.2	4	0.8	2.6	ns

⁽¹⁾ All typical values are at $T_A = 25^{\circ}C$. (2) For I/O ports, the parameter I_{OZ} includes the input leakage current.







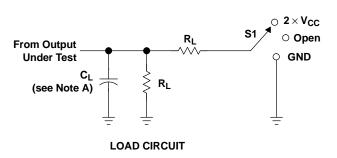
Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER		TEST CONDITIONS	V _{CC} = 0.8 V TYP	V _{CC} = 1.2 V TYP	V _{CC} = 1.5 V TYP	V _{CC} = 1.8 V TYP	V _{CC} = 2.5 V TYP	UNIT
Power enable dissipation capacitance Output	Outputs enabled	f = 10 MHz	20	21	21	23	27	٥٤	
	Outputs disabled	1 = 10 MIHZ	1	1	1	1	1	pF	

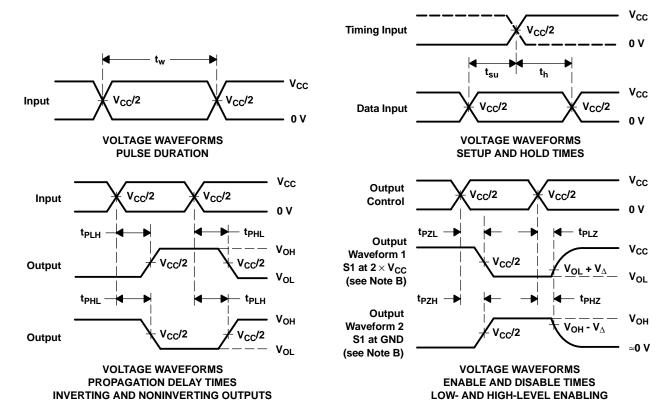


PARAMETER MEASUREMENT INFORMATION



TEST	S1
t _{PLH} /t _{PHL}	Open
t _{PLZ} /t _{PZL} t _{PHZ} /t _{PZH}	2×V _{CC} GND
'PHZ/'PZH	GIND

V _{CC}	CL	R _L	$oldsymbol{V}_\Delta$
0.8 V	15 pF	2 k Ω	0.1 V
1.2 V \pm 0.1 V	15 pF	2 k Ω	0.1 V
1.5 V \pm 0.1 V	15 pF	2 k Ω	0.1 V
1.8 V \pm 0.15 V	15 pF	2 k Ω	0.15 V
2.5 V \pm 0.2 V	15 pF	2 k Ω	0.15 V
1.8 V \pm 0.15 V	30 pF	1 k Ω	0.15 V
2.5 V \pm 0.2 V	30 pF	500 Ω	0.15 V



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , slew rate \geq 1 V/ns.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en}.
 - G. t_{PLH} and t_{PHL} are the same as t_{pd}.
 - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms



PACKAGE OPTION ADDENDUM

27-Dec-2019

PACKAGING INFORMATION

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Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
SN74AUC245RGYR	ACTIVE	VQFN	RGY	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	MS245	Samples
SN74AUC245ZQNR	NRND	BGA MICROSTAR JUNIOR	ZQN	20	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	MS245	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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27-Dec-2019

PACKAGE MATERIALS INFORMATION

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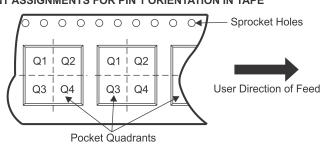
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

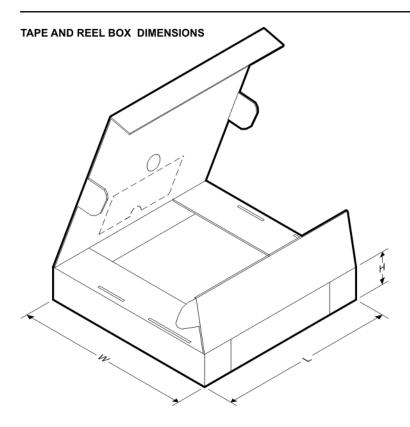
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUC245RGYR	VQFN	RGY	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1
SN74AUC245ZQNR	BGA MI CROSTA R JUNI OR	ZQN	20	1000	330.0	12.4	3.3	4.3	1.6	8.0	12.0	Q1

www.ti.com 12-Feb-2019



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUC245RGYR	VQFN	RGY	20	3000	367.0	367.0	35.0
SN74AUC245ZQNR	BGA MICROSTAR JUNIOR	ZQN	20	1000	350.0	350.0	43.0

3.5 x 4.5, 0.5 mm pitch

PLASTIC QUAD FGLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





PLASTIC QUAD FLATPACK - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC QUAD FLATPACK - NO LEAD



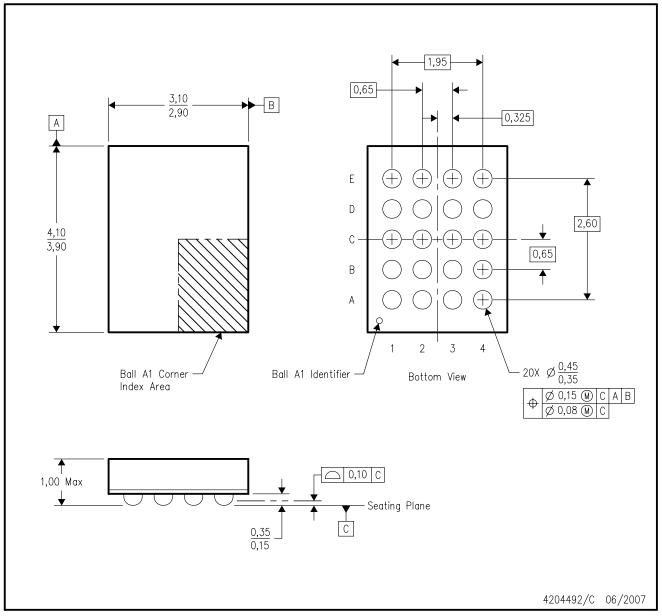
NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



ZQN (R-PBGA-N20)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BC-2.
- D. This package is lead-free. Refer to the 20 GQN package (drawing 4200704) for tin-lead (SnPb).



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